Thyristor Semiconductor Device - Page 1 of 1



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| Inclosure Material: |
|--|
| Metal |
| Overall Length: |
| Between 0.330 inches and 0.505 inches |
| End Application: |
| 4920-01-049-0223 |
| Mounting Facility Quantity: |
| 1 |
| Internal Configuration: |
| Junction contact |
| Mounting Method: |
| Threaded stud |
| Features Provided: |
| Hermetically sealed case |
| Overall Width Across Flats: |
| 0.544 inches |
| Thread Size: |
| 0.250 inches |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 300.0 repetitive peak reverse voltage |
| Current Rating Per Characteristic: |
| 5.00 milliamperes forward current, average of standard range |
| Power Rating Per Characteristic: |
| 25.0 watts small-signal input power, common-collector blank |
| Maximum Operating Tempurature Per Measurement Point: |
| 120.0 degrees celsius junction |
| Special Features: |
| Junction pattern arrangement: npnp |
| Thread Series Designator: |
| Unf |
| Terminal Type And Quantity: |
| 1 threaded stud and 2 tab, solder lug |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
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